









TVS2701

JAJSGB4A - SEPTEMBER 2018-REVISED DECEMBER 2018

TVS2701 27V双方向、フラットクランプ・サ-

特長

- 産業用信号ライン向け1kV、42ΩのIEC 61000-4-5サージ・テストに耐える保護機能
- 双方向の極性により、バイポーラ信号処理や誤配 線に対して保護
- クランプ電圧:34V (サージ電流27A (8/20μs) 時)
- スタンドオフ電圧:±27V
- 小型の3mm×3mm² SONフットプリント
- 125℃ で 27A、8/20µs のサージ電流の反復ストラ イクを 5,000 回吸収
- 強力なサージ保護
 - IEC61000-4-5 (8/20µs): 27A
 - IEC61643-321 (10/1000µs): 3.5A
- 低リーク電流
 - 27°Cで0.8nA(標準値)
 - 85°Cで400nA(最大値)
- 低容量: 57pF
- レベル4 IEC 61000-4-2に準拠したESD保護機能を 内蔵

アプリケーション

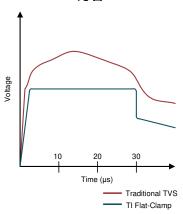
- 産業用センサI/O
- PLC I/Oモジュール
- アナログ入力
- 家電製品
- 医療用機器
- ビルディング・オートメーション

型番	パッケージ	本体サイズ(公称)
TVS2701	SON (8)	3.00mm×3.00mm

製品情報(1)

(1) 提供されているすべてのパッケージについては、巻末の注文情報 を参照してください。

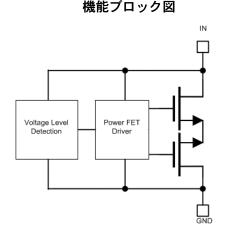
8/20µsのサージ・イベントに対する電圧クランプの



3 概要

TVS2701デバイスは、最大27AのIEC 61000-4-5フォルト 電流をシャントし、大電力の過渡事象や落雷からシステム を保護します。このデバイスは、一般的な産業用信号線の EMC 要件である、 42Ω のインピーダンスで結合した 1kVの IEC 61000-4-5 開路電圧に耐えます。 TVS2701は帰 還機構を使用して、フォルト中の正確なフラット・クランプを 確保し、システムがさらされる電圧を、従来型のTVSダイ オードよりも低く保ちます。厳格な電圧レギュレーションに より、設計者は許容電圧が低いシステム部品でも安心して 選択でき、堅牢性を損なうことなくシステムのコストと複雑 性を低減できます。TVS2701は±27Vの範囲で動作する ため、逆配線に対する保護を必要とするシステムでも動作 できます。

さらに、TVS2701はスペースの制約が厳しいアプリケー ション用に設計された小型のSONフットプリントで供給され るため、標準のSMAおよびSMBパッケージと比較して大 幅なサイズ低減が可能です。デバイスのリーク電流と静電 容量が小さいため、保護するラインへの影響も最小限に 抑えられます。製品のライフサイクル全体にわたる堅牢な 保護を確保するため、TIはTVS2701をテストし、125℃ で5000回の反復サージに対してデバイス性能に変化がな いことを確認しています。





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4 改訂履歴

2018年9月	発行のものから更新	Page
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5 概要(続き)

TVS2701はTIのフラット・クランプ・サージ・デバイス・ファミリの製品です。フラット・クランプ・ファミリの詳細については、『効率的なシステム保護のためのフラット・クランプ・サージ保護技術』ホワイト・ペーパーを参照してください。



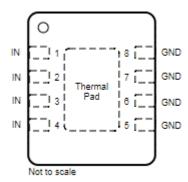
6 Device Comparison Table

DEVICE	V _{rwm}	V _{clamp} at I _{pp}	I _{pp} (8/20 μs)	Leakage at V _{rwm}	POLARITY	Package
TVS0500	5	9.2 V	43 A	0.07 nA	Unidirectional	DRV (SON-6)
TVS0701	7	11 V	30 A	0.25 nA	Bidirectional	DRB (SON-8)
TVS1400	14	18.6 V	43 A	2 nA	Unidirectional	DRV (SON-6)
TVS1401	14	20.5 V	30 A	1.1 nA	Bidirectional	DRB (SON-8)
TVS1800	18	22.8 V	40 A	0.3 nA	Unidirectional	DRV (SON-6)
TVS1801	18	27.4 V	30 A	0.4 nA	Bidirectional	DRB (SON-8)
TVS2200	22	27.7 V	40 A	3.2 nA	Unidirectional	DRV (SON-6)
TVS2201	22	29.6 V	30 A	2 nA	Bidirectional	DRB (SON-8)
TVS2700	27	32.5 V	40 A	1.7 nA	Unidirectional	DRV (SON-6)
TVS2701	27	34 V	27 A	0.8 nA	Bidirectional	DRB (SON-8)
TVS3300	33	38 V	35 A	19 nA	Unidirectional	DRV (SON-6), YZF (WCSP)
TVS3301	33	40 V	27 A	2.5 nA	Bidirectional	DRB (SON-8)



7 Pin Configuration and Functions





Pin Functions

	PIN	TYPE	DESCRIPTION
NAME	DRB	ITPE	DESCRIPTION
IN	1, 2, 3, 4	IN	Surge Protected Channel
GND	5, 6, 7, 8	GND	Ground
FLOAT	Exposed Thermal Pad	NC	Exposed Thermal Pad Must Be Floating



8 Specifications

8.1 Absolute Maximum Ratings

 $T_A = 27^{\circ}C$ (unless otherwise noted)⁽¹⁾

	MIN	MAX	UNIT				
IEC 61000-4-5 Current (8/20 μs), T _A < 125°C		±27	Α				
IEC 61000-4-5 Power (8/20 μs)		950	W				
IEC 61643-321 Current (10/1000 μs)		±3.5	Α				
IEC 61643-321 Power (10/1000 μs)		120	W				
IEC 61000-4-4 EFT Protection		±80	А				
DC Current		25	mA				
Ambient Operating Temperature	-40	125	°C				
Storage Temperature	-65	150	°C				
	IEC 61000-4-5 Power (8/20 μs) IEC 61643-321 Current (10/1000 μs) IEC 61643-321 Power (10/1000 μs) IEC 61000-4-4 EFT Protection DC Current Ambient Operating Temperature	IEC 61000-4-5 Current (8/20 μs), T _A < 125°C IEC 61000-4-5 Power (8/20 μs) IEC 61643-321 Current (10/1000 μs) IEC 61643-321 Power (10/1000 μs) IEC 61000-4-4 EFT Protection DC Current Ambient Operating Temperature	IEC 61000-4-5 Current (8/20 μs), $T_A < 125^{\circ}$ C ±27 IEC 61000-4-5 Power (8/20 μs) 950 IEC 61643-321 Current (10/1000 μs) ±3.5 IEC 61643-321 Power (10/1000 μs) 120 IEC 61000-4-4 EFT Protection ±80 DC Current 25 Ambient Operating Temperature -40 125				

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Rating may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Condition. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

8.2 ESD Ratings - JEDEC

V	Floatroatatic disabores	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±2000	l v
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specificationJESD22-C101, all pins (2)	±500	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

8.3 ESD Ratings - IEC

			VALUE	UNIT
V	Flootrastatio discharge	IEC 61000-4-2 contact discharge	±8	14/
V(ESD)	V _(ESD) Electrostatic discharge	IEC 61000-4-2 air-gap discharge	±15	kV

8.4 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{RWM}	Reverse Stand-Off Voltage		±27		V

8.5 Thermal Information

		TVS2701	
	THERMAL METRIC ⁽¹⁾	DRB (SON)	UNIT
		8 PINS	
R _{qJA}	Junction-to-ambient thermal resistance	52	°C/W
R _{qJC(top)}	Junction-to-case (top) thermal resistance	56.1	°C/W
R_{qJB}	Junction-to-board thermal resistance	24.9	°C/W
Y_{JT}	Junction-to-top characterization parameter	2.1	°C/W
Y_{JB}	Junction-to-board characterization parameter	24.8	°C/W
R _{qJC(bot)}	Junction-to-case (bottom) thermal resistance	9.8	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



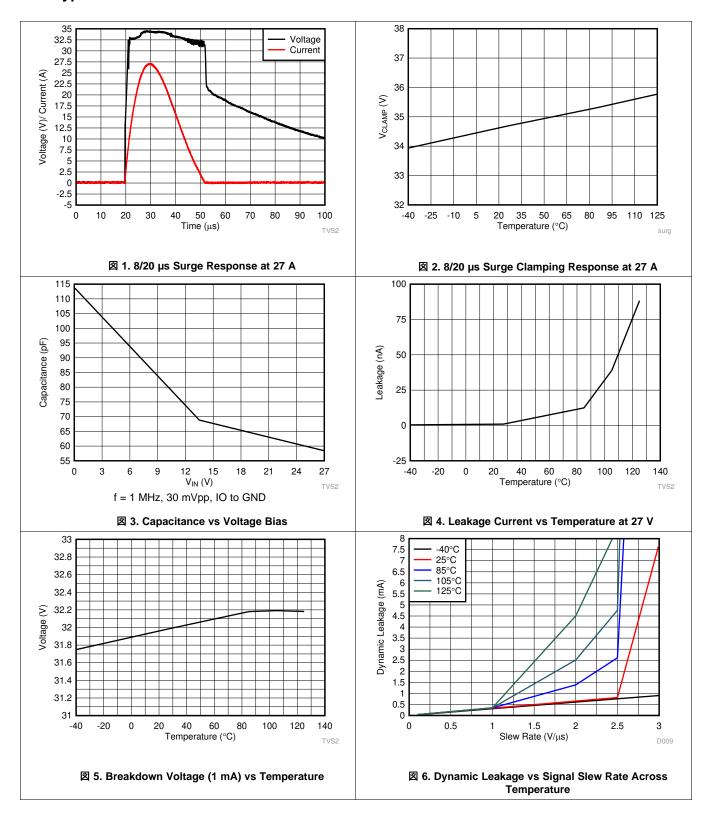
8.6 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Lookaga Current	Measured at V _{IN} = ±V _{RWM} , T _A = 27°C		0.8	30	~ ^
I _{LEAK}	Leakage Current	Measured at $V_{IN} = \pm V_{RWM}$, $T_A = 85$ °C			400	nA
V_{BR}	Break-down Voltage	I _{IN} = ±1mA	29.6	32		V
V	Clares Valtaria	±I _{pp} IEC 61000-4-5 Surge (8/20 μs), V _{IN} = 0 V before surge, T _A = 27°C		34	35.7	V
V_{CLAMP}	Clamp Voltage	$\pm I_{PP}$ IEC 61000-4-5 Surge (8/20 μ s), V_{IN} = $\pm V_{RWM}$ before surge, T_A = 125°C			37.3	V
R_{DYN}	8/20 μs surge dynamic resistance	Calculated from V_{CLAMP} at .5*I _{PP} and I _{PP} surge current, $T_A = 25^{\circ}C$		40		$m\Omega$
C_{IN}	Input pin capacitance	$V_{IN} = V_{RWM}$, f = 1 MHz, 30 m V_{pp} , IO to GND		57		pF
CD.	Mayimum Clay Data	$0-\pm V_{RWM}$ rising edge, sweep rise time and measure slew rate when $I_{PEAK}=1$ mA, $T_A=27^{\circ}C$	2.5		Miss	
SR	Maximum Slew Rate	$0-\pm V_{RWM}$ rising edge, sweep rise time and measure slew rate when $I_{PEAK}=1$ mA, $T_A=85^{\circ}C$		1.0		V/µs

TEXAS INSTRUMENTS

8.7 Typical Characteristics



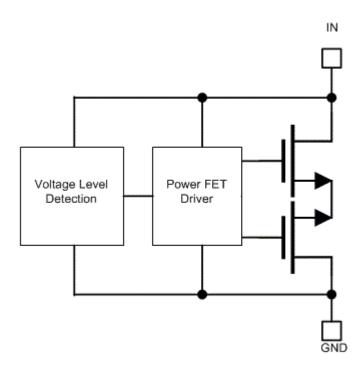


9 Detailed Description

9.1 Overview

The TVS2701 is a bidirectional precision clamp with two integrated FETs driven by a feedback loop to tightly regulate the input voltage during an overvoltage event. This feedback loop leads to a very low dynamic resistance, giving a flat clamping voltage during transient overvoltage events like a surge.

9.2 Functional Block Diagram



9.3 Feature Description

The TVS2701 is a precision clamp that handles 27 A of IEC 61000-4-5 8/20- μ s surge pulse. The flat clamping feature helps keep the clamping voltage very low to keep the downstream circuits from being stressed. The flat clamping feature can also help end-equipment designers save cost by opening up the possibility to use lowercost, lower voltage tolerant downstream ICs. This device provides a bidirectional operating range, with a symmetrical V_{RWM} of ± 27 V designed for applications that have bipolar input signals or that must withstand reverse wiring conditions. The TVS2701 has minimal leakage at V_{RWM} , designed for applications where low leakage and power dissipation is a necessity. Built-in IEC 61000-4-2 and IEC 61000-4-4 ratings make it a robust protection solution for ESD and EFT events and the TVS2701 wide ambient temperature range of -40° C to $+125^{\circ}$ C enables usage in harsh industrial environments.

9.4 Device Functional Modes

9.4.1 Protection Specifications

The TVS2701 is specified according to both the IEC 61000-4-5 and IEC 61643-321 standards. This enables usage in systems regardless of which standard is required by relevant product standards or best matches measured fault conditions. The IEC 61000-4-5 standard requires protection against a pulse with a rise time of 8 μ s and a half-length of 20 μ s, while the IEC 61643-321 standard requires protection against a much longer pulse with a rise time of 10 μ s and a half-length of 1000 μ s.



Device Functional Modes (continued)

The positive and negative surges are imposed to the TVS2701 by a combination wave generator (CWG) with a $2-\Omega$ coupling resistor at different peak voltage levels. For powered-on transient tests that need power supply bias, inductances are used to decouple the transient stress and protect the power supply. The TVS2701 is post-tested by assuring that there is no shift in device breakdown or leakage at V_{RWM} .

In addition, the TVS2701 has been tested according to IEC 61000-4-5 to pass a ± 1 -kV surge test through a 42- Ω coupling resistor and a 0.5- μ F capacitor. This test is a common test requirement for industrial signal I/O lines and the TVS2701 precision clamp can be used in applications that have that requirement.

The TVS2701 integrates IEC 61000-4-2 level 4 ESD Protection and 80 A of IEC 61000-4-4 EFT Protection. These combine to ensure that the device can protect against most common transient test requirements.

For more information on TI's test methods for Surge, ESD, and EFT testing, refer to the *IEC 61000-4-x Tests for TI's Protection Devices* application report.

9.4.2 Reliability Testing

To ensure device reliability, the TVS2701 is characterized against 5000 repetitive pulses of 25-A IEC 61000-4-5 8/20-µs surge pulses at 125°C. The test is performed with less than 10 seconds between each pulse at high temperature to simulate worst-case scenarios for fault regulation. After each surge pulse, the TVS2701 clamping voltage, breakdown voltage, and leakage are recorded to ensure that there is no variation or performance degradation. By ensuring robust, reliable, high temperature protection, the TVS2701 enables fault protection in applications that must withstand years of continuous operation with no performance change.

9.4.3 Zero Derating

Unlike traditional diodes, the TVS2701 has zero derating of maximum power dissipation and ensures robust performance up to 125°C. Traditional TVS diodes lose up to 50% of their current carrying capability when at high temperatures, so a surge pulse above 85°C ambient can cause failures that are not seen at room temperature. The TVS2701 prevents this so the designer can see the surge protection regardless of temperature. Because of this, Flat-Clamp devices can provide robust protection against surge pulses that occur at high ambient temperatures, as shown in TI's TVS Surge Protection in High-Temperature Environments application report.

9.4.4 Bidirectional Operation

The TVS2701 is a bidirectional TVS with a symmetrical operating region. This allows for operation with positive and negative voltages, rather than just positive voltages like the unidirectional TVS2700. This allows for single chip protection for applications where the signal is expected to operate below 0 V or where there is a need to withstand a large common-mode voltage. In addition, in many cases, there is a system requirement to be able to withstand reverse wiring conditions, in many cases where a high voltage signal is accidentally applied to the system ground and a ground is accidentally applied to the input terminal. This causes a large reverse voltage on the TVS diode that the device must be able to withstand. The TVS2701 is designed to not break down or see failures under reverse wiring conditions, for applications that must withstand these miswiring issues.

注

If the applied signal is not expected to go below 0 V, a unidirectional device will clamp much lower in the reverse direction and should be used. In this case, the recommended device would be the TVS2700.

9.4.5 Transient Performance

During large transient swings, the TVS2701 will begin clamping the input signal to protect downstream conditions. While this prevents damage during fault conditions, it can cause leakage when the intended input signal has a fast slew rate. To keep power dissipation low and remove the chance of signal distortion, TI recommends that the designer keep the slew rate of any input signal on the TVS2701 below 2.5 V/ μ s at room temperature and below 1.0 V/ μ s at 85°C shown in Ξ 6. Faster slew rates will cause the device to clamp the input signal and draw current through the device for a few microseconds, increasing the rise time of the signal. This will not cause any harm to the system or to the device, however if can cause device overheating if the fast input voltage swings occur regularly.



10 Application and Implementation

注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

The TVS2701 can be used to protect any power, analog, or digital signal from transient fault conditions caused by the environment or other electrical components. A common application will be protecting both the PLC and sensor transmitter in industrial applications, as shown. More detail will be given on the protection on the PLC side as the input signal is connected to the input of a multiplexer.

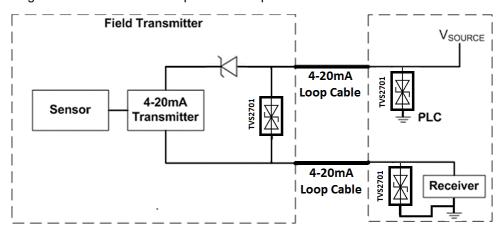


図 7. TVS2701 Application Example

10.2 Typical Application

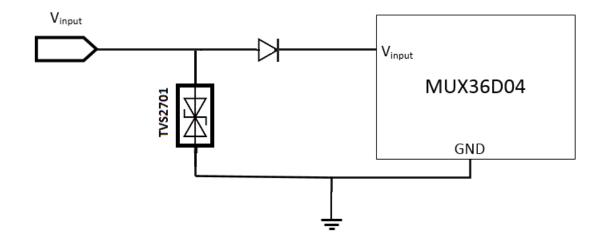


図 8. TVS2700 Application Schematic

Typical Application (continued)

10.2.1 Design Requirements

A typical operation for the TVS2701 would be in a multi-channel PLC protecting an analog input, shown in 🗵 8. In this example, a TVS2701 is protecting the input to a MUX36D04, a four channel input multiplexer with a supply maximum at 36 V. In addition, the application must be able to withstand reverse wiring conditions with no damage caused to the input circuitry. Without any input protection, this input voltage will rise to hundreds of volts for multiple microseconds and violate the absolute maximum input voltage and harm the device if a surge event is caused by lightning, coupling, ringing, or any other fault condition. Tl'd Flat-Clamp technology provides surge protection diodes that can maximize the useable voltage range and clamp at a safe level for the system.

10.2.2 Detailed Design Procedure

If the TVS2701 is in place to protect the device, the voltage will rise to the breakdown of the diode at 32 V during a surge event. The TVS2701 will then turn on to shunt the surge current to ground. With the low dynamic resistance of the TVS2701, even large amounts of surge current will have minimal impact on the clamping voltage. The dynamic resistance of the TVS2701 is around 40 m Ω , which means a 25-A surge current will cause a voltage raise of 25 A x 40 m Ω = 1 V. Because the device turns on at 32 V, this means the module input will be exposed to a maximum of 32 V + 1 V = 33 V during surge pulses, well within the MUX36D04 absolute maximum.

In addition, because the TVS2701 is a bidirectional device it is designed to withstand reverse wiring conditions. When the supplies is wired backwards, it applies -27 V to the V_{INPUT} relative to ground, which does not break down the TVS diode, and does not damage the input to the MUX36D04 because of the reverse current protection diode. If a unidirectional diode like the TVS2700 were used in this case, the -27 V would cause the diode to shunt current until it overheat and breaks.

Finally, the small size of the device also improves fault protection by lowering the effect of fault current coupling onto neighboring traces. The small form factor of the TVS2701 allows the device to be placed extremely close to the input connector, which lowers the length of the path fault current going through the system compared to larger protection solutions.

10.2.3 Application Curves

When a surge is applied to the system with the TVS2701, the device will clamp the surge as shown in 29.

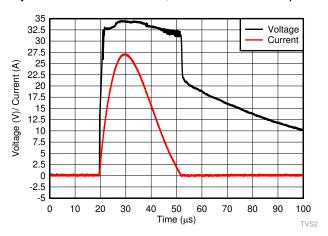


図 9. TVS2701 Surge Response at 27 A

11 Power Supply Recommendations

The TVS2701 is a clamping device so there is no need to power it. To ensure the device functions properly do not violate the recommended V_{IN} voltage range (-27 V to 27 V) .



12 Layout

12.1 Layout Guidelines

The optimum placement is close to the connector. EMI during an ESD event can couple from the tested trace to other nearby unprotected traces, which could result in system failures. The PCB designer must minimize the possibility of EMI coupling by keeping all unprotected traces away from protected traces between the TVS and the connector. Route the protected traces straight. Use rounded corners with the largest radii possible to eliminate any sharp corners on the protected traces between the TVS2701 and the connector. Electric fields tend to build up on corners, which could increase EMI coupling.

Ensure that the thermal pad on the layout is floating rather than grounded. Grounding the thermal pad will impede the operating range of the TVS2701, and can cause failures when the applied voltage is negative. A floating thermal pad allows the maximum operating range without sacrificing any transient performance.

12.2 Layout Example

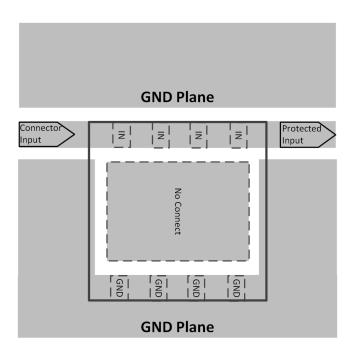


図 10. TVS2701 Layout



13 デバイスおよびドキュメントのサポート

13.1 ドキュメントのサポート

13.1.1 関連資料

関連資料については、以下を参照してください。

- 『効率的なシステム保護のためのフラット・クランプ・サージ保護技術』
- 『TI の保護デバイスに対する IEC 61000--4-x テスト』
- 『高温環境での TVS サージ保護』

13.2 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、ti.comのデバイス製品フォルダを開いてください。右上の「アラートを受け取る」をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取れます。変更の詳細については、修正されたドキュメントに含まれている改訂履歴をご覧ください。

13.3 コミュニティ・リソース

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

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13.4 商標

E2E is a trademark of Texas Instruments.

13.5 静電気放電に関する注意事項



すべての集積回路は、適切なESD保護方法を用いて、取扱いと保存を行うようにして下さい。



静電気放電はわずかな性能の低下から完全なデバイスの故障に至るまで、様々な損傷を与えます。高精度の集積回路は、損傷に対して敏感であり、極めてわずかなパラメータの変化により、デバイスに規定された仕様に適合しなくなる場合があります。

13.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

14 メカニカル、パッケージ、および注文情報

以降のページには、メカニカル、パッケージ、および注文に関する情報が記載されています。この情報は、そのデバイスについて利用可能な最新のデータです。このデータは予告なく変更されることがあり、ドキュメントが改訂される場合もあります。本データシートのブラウザ版を使用されている場合は、画面左側の説明をご覧ください。

www.ti.com 23-May-2025

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
TVS2701DRBR	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	1PTP
TVS2701DRBR.A	Active	Production	SON (DRB) 8	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	1PTP

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

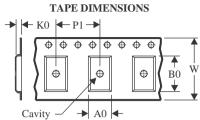
⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE MATERIALS INFORMATION

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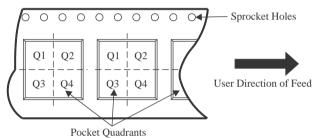
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	U	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TVS2701DRBR	SON	DRB	8	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2

PACKAGE MATERIALS INFORMATION

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*All dimensions are nominal

	Device	Package Type	Package Drawing	Pins SPQ		Length (mm)	Width (mm)	Height (mm)	
ı	TVS2701DRBR	SON	DRB	8	3000	338.0	355.0	50.0	



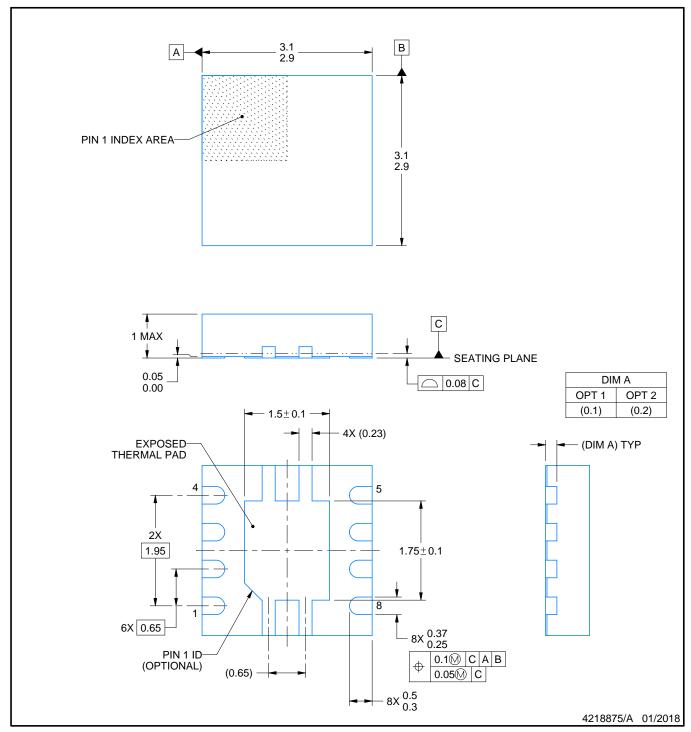
Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4203482/L





PLASTIC SMALL OUTLINE - NO LEAD

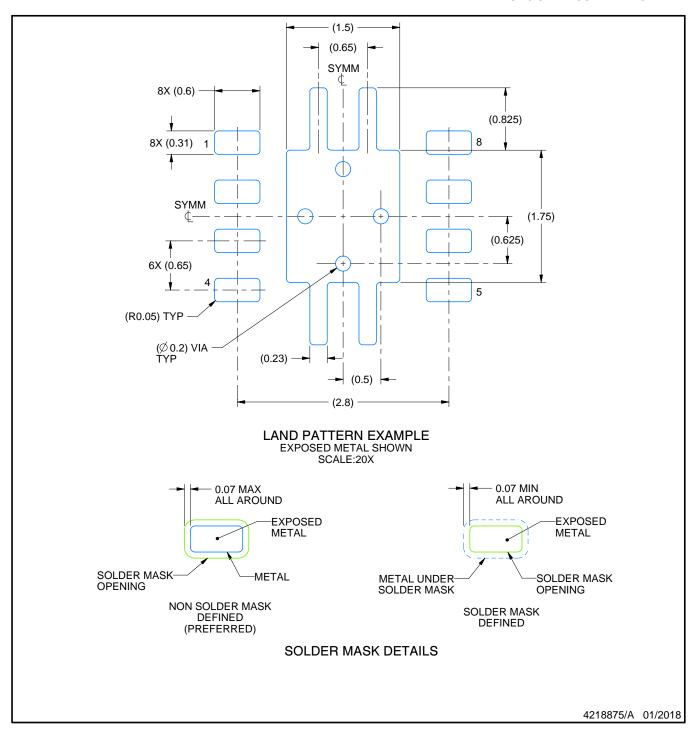


NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



PLASTIC SMALL OUTLINE - NO LEAD

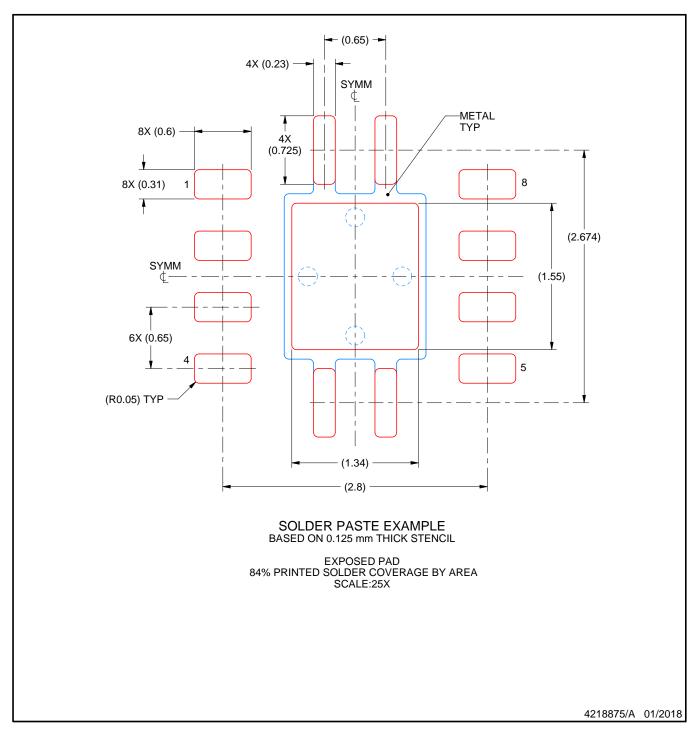


NOTES: (continued)

- 4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



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